



BSS84V

DUAL P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Product Summary

V(BR)DSS	Rds(on) Max	І р Т _А = +25°С
-50V	10Ω @ V _{GS} = -5V	-130mA

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General purpose interfacing switches
- Power management functions
- Analog switches

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

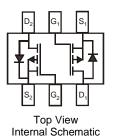
https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 3
 - Terminal Connections: See Diagram
 - Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

Notes:

Part Number	Package	Packing			
	T dekage	Qty.	Carrier		
BSS84V-7	SOT563	3000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

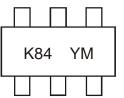
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

SOT563

Top View



Marking Information



K84 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Dale Code Rey												
Year	2005		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	S		J	K	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characterist	tic	Symbol	Value	Units
Drain-Source Voltage		Vdss	-50	V
Drain-Gate Voltage (Note 5)		Vdgr	-50	V
Gate-Source Voltage	Continuous	Vgss	±20	V
Drain Current (Note 6)	Continuous	lp	-130	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation	PD	150	mW	
Thermal Resistance, Junction to Ambient	Reja	833	°C/W	
Operating and Storage Temperature Range	TJ, Tsтg	-55 to +150	°C	

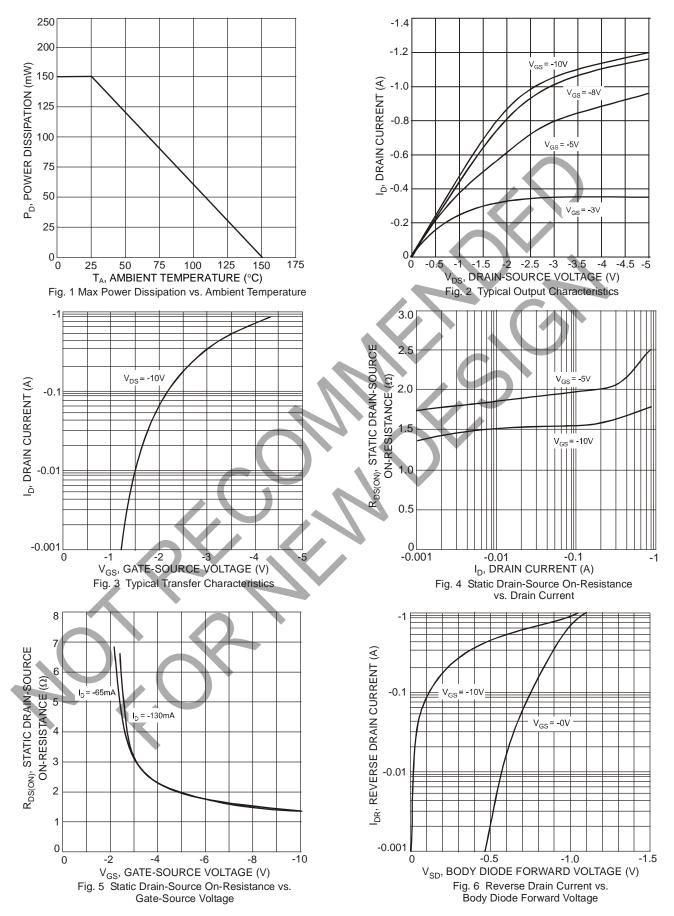
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-50	-75	—	V	$V_{GS} = 0V, I_D = -250\mu A$
		_		-1	μA	$V_{DS} = -50V, V_{GS} = 0V, T_{J} = +25^{\circ}C$
Zero Gate Voltage Drain Current	IDSS	—	_	-2	μA	V _{DS} = -50V, V _{GS} = 0V, T _J = +125°C
	1055	—	—	-100	nA	$V_{DS} = -25V, V_{GS} = 0V, T_J = +25^{\circ}C$
Gate-Body Leakage	Igss	—		±50	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	-0.8	-1.6	-2.0	V	V _{DS} = V _{GS} , I _D = -1mA
Static Drain-Source On-Resistance	R _{DS(ON)}		2	10	Ω	$V_{GS} = -5V, I_D = -0.100A$
Forward Transconductance	g fs	0.05	—	—	S	$V_{DS} = -25V, I_D = -0.1A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	_	_	45	pF	
Output Capacitance	Coss	_	—	25	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	—	12	pF	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	td(on)		10	_	ns	V _{DD} = -30V, I _D = -0.27A
Turn-Off Delay Time	t _{D(OFF)}		18	—	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$

5. R_{GS} ≤ 20kΩ. Notes:

6. Device mounted on FR-4 PCB, 1inch x 0.85inch x 0.062inch; pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html. 7. Short duration pulse test used to minimize self-heating effect.



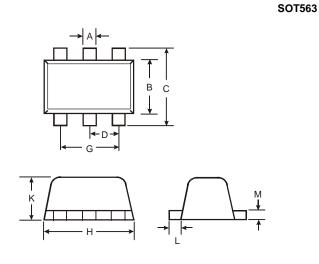


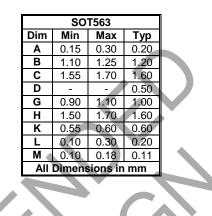


BSS84V

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





2.2

1.2

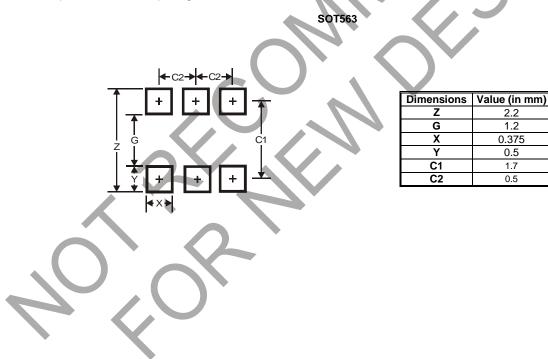
0.5

1.7

0.5

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





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